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APPLICATION NO	FILI	NG DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION N
09/895,579	06/	/29/2001	Brian S. Doyle	42390P11362	6936
8791	7590	05:01:2002	TATMAN.		
		FF TAYLOR &	EXAM	EXAMINER	
	SHIRE BOU ELES, CA - 9	LEVARD, SEVE 0025	ENTH FLOOR	NHU. DAVID	
				ART UNIT	PAPER NUMBER
				2818	

DATE MAILED: 05/01/2002

Please find below and/or attached an Office communication concerning this application or proceeding.

•		Application No.	Ar Cant(s)
		09/895,579	DOYLE ET AL
	Office Action Summary	Examiner	Art Unit
		David Nhu	2818
Period fo	The MAILING DATE of this communication app or Reply	ears on the cover sheet with the c	orrespondence address
- External file of the control of th	ORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. nsions of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. Period for reply specified above is less than thirty (30) days, a reply operiod for reply is specified above, the maximum statutory period we reto reply within the set or extended period for reply within the set or exte	within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from cause the application to become ARABDONE	nely filed s will be considered timely. the mailing date of this communication.
Status			
1)[]	Responsive to communication(s) filed on 25 A	<u>pril 2002</u> .	
2a) <u></u>		s action is non-final.	
3) Dispositi	Since this application is in condition for allowa closed in accordance with the practice under <i>E</i> on of Claims	nce except for formal matters, pr Ex parte Quayle, 1935 C.D. 11, 4	osecution as to the merits is 53 O.G. 213.
4)[-	Claim(s) <u>1-19</u> is/are pending in the application.		
	4a) Of the above claim(s) <u>1-13</u> is/are withdrawn	from consideration.	
5)	Claim(s) is/are allowed.		
6)[-]	Claim(s) <u>14-18</u> is/are rejected.		
7)[-	Claim(s) <u>19</u> is/are objected to.		
	Claim(s) are subject to restriction and/or on Papers	election requirement.	
9) 🔲 🗆	The specification is objected to by the Examiner.		
	he drawing(s) filed on is/are: a)□ accept		niner.
	Applicant may not request that any objection to the		
11) 🗌 🏾	he proposed drawing correction filed on		
	If approved, corrected drawings are required in repl		
12) 🔲 7	he oath or declaration is objected to by the Exa	miner.	
Priority u	nder 35 U.S.C. §§ 119 and 120		
13)	Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a)	-(d) or (f).
	☐ All b) ☐ Some * c) ☐ None of:	,	
	1. Certified copies of the priority documents	have been received.	
	2. Certified copies of the priority documents		n No.
	3. Copies of the certified copies of the priorit application from the International Bure ee the attached detailed Office action for a list of	y documents have been received	in this National Stage
	cknowledgment is made of a claim for domestic	•	
a)	☐ The translation of the foreign language provi	isional application has been rece	ived.
Attachment(		priority under 33 0.3.0. 99 120 8	anu/01 1∠1.
1) Notice 2) Notice	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review (PTO-948) ation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal Pa	PTO-413) Paper No(s) tent Application (PTO-152)
S Patent an 1 Tra PTO-326 (Rev		on Summary	Part of Paper No. 6

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#### **DETAILED ACTION**

### Election/Restrictions

1. Applicant's election of Group II (Claims 14-19) in page No.5 is acknowledge.

Claims 14-19 are remained for examination. Accordingly, claims 1-13 are withdrawn from consideration as being directed to a non-elected invention.

### Specifications

### **Content of Specification**

2. The disclosure is objected to because of the following informalities: Description of the Related Art is missing. Appropriate correction is required.

**Background of the Invention**: The specification should set forth the Background of the Invention in two parts:

- (a) <u>Field of the Invention</u>: A statement of the field of art to which the invention pertains. This statement may include a paraphrasing of the applicable U.S. patent classification definitions of the subject matter of the claimed invention. This item may also be titled "Technical Field."
- (b) <u>Description of the Related Art</u>: A description of the related art known to the applicant and including, if applicable, references to specific related art and problems involved in the prior art which are solved by the applicant's invention. This item may also be titled "Background Art."

# Claim Rejections - 35 USC § 112

3. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

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4. Claims 14- 16 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Claim 14, line 5, " **the** top of the relaxed SiGe layer " lacks a clear antecedent basis. Claims 15, 16 are rejected due to the rejections of the parent claim.

# Claim Rejections - 35 USC § 103

- 5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office Action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 6. Claims 14 is rejected under 35 U.S.C. 103(a) as being unpatentable over Godbey et al (5,013,681) in view of Tejewani et al (5,310,451).

**Regarding claim 14**, see Godbey, figures 1-13, and related text on col. 1-8, which disclose a wafer 20 comprising a silicon layer 22; a relaxed SiGe layer 22 (see figure 1, col. 3, lines 12-59).

It is noted that Godbey fails to teach a strained silicon layer in contact with the relaxed SiGe layer, the strained silicon layer being transferred to a top of the relaxed SiGe layer by a heat treatment. However, Tejewani, figures 1-8, and related text on col. 1-12, (figures 1-3, col. 4, lines 54-67, col. 5, lines 1-67, col. 6, lines 1-67, col, 7, lines 1-7), also teach "a SOI structure using SiGe layer", further teach a strained silicon layer 22 in contact with the relaxed SiGe

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layer 20, the strained silicon layer being transferred to a top of the relaxed SiGe layer by a heat treatment.

It would have been obvious to one having ordinary skill in the art at the time of the present invention to apply the teachings of Tejewani into Godbey as both are related to the same subject matter of providing an improved silicon-on-insulator (SOI) fabrication process using SiGe etch stop layer.

## Claim Rejections - 35 USC § 103

- 6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office Action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 7. Claims 17, 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tejewani et al (5,310,451) in view of Godbey et al (5,013,681).

**Regarding claim 17**, see Tejewani, figures 1-8, and related text on col. 1-12, which disclose a wafer 110 comprising a silicon layer 30; a SiO2 layer 32 in contact with the silicon layer (see figure 2, col. 7, lines 22-43).

It is noted that Tejewani fails to teach the step of a strained silicon layer on top of the SiO2 layer, the strained silicon layer being transferred to an oxidized wafer by a heat treatment. However, Godbey, figures 1-13, and related text on col. 1-8, (figures 1-6, col. 3-5, lines 1-67, col. 4, lines 20-27) teach the step of a strained silicon layer 26 on top of the SiO2 layer 29, the strained silicon layer being transferred to an oxidized wafer 30 by a heat treatment.

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Regarding claim 18, (Godbey, figures 5, 6, col. 4, lines 20-27) teaches the oxidized wafer contains a relaxed SiGe layer 24.

It would have been obvious to one having ordinary skill in the art at the time of the present invention to apply the teachings of Godbey into Tejewani as both are related to the same subject matter of providing an improved silicon-on-insulator (SOI) fabrication process using SIGe etch stop process.

# Allowable Subject Matter

8. Claims 15, 16, and 19 are **objected** to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Claims 15-16 would be allowable if written to overcome the rejection under 35 U.S.C. 112 set forth in this Office Action and to include all of the limitation of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter: Claims 15, 16, and 19 include allowable subject matter since the prior made of record and considered pertinent to the applicant's disclosure does not teach or suggest the claimed limitations. Because Godbey (5,013,681) and Tejwani (5,310,451) taken individually or in combination, do not teach a relaxed SiGe layer contains an embrittle region; the embrittle report is created by implanting hydrogen ions.

#### Conclusion

- 9. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure: Beyer'535 is cited as of interest.
- 10. A shortened statutory period for response to this action is set to expired 3 (three) months and 0 (zero) day from the date of this letter. Failure to respond within the period for response will cause the application to become abandoned (see 710.02 (b)).
- 11. Any inquiry concerning this communication on earlier communications from the examiner should be directed to David Nhu, (703) 306-5796. The examiner can normally be reached on Monday-Friday from 7:30 AM to 5:00 PM. The examiner's supervisor, David Nelms can be reached on (703) 308-4910.

The fax phone number for the organization where this application or proceeding is assigned is (703) 308-7724.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

David Nhu PN

April 28, 2002

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